AUTOMOTIVE

RoHS

COMPLIANT

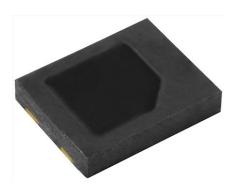
FREE

GREEN (5-2008)



# Vishay Semiconductors

## Silicon PIN Photodiode



#### **DESCRIPTION**

VEMD5160X01 is a high speed and high sensitive PIN photodiode with a highly linear photoresponse. It is a low profile surface mount device (SMD) including the chip with a 7.5 mm<sup>2</sup> sensitive area and a daylight blocking filter matched with IR emitters operating at wavelength 850 nm or 890 nm.

#### **FEATURES**

- Package type: surface mount
- · Package form: top view
- Dimensions (L x W x H in mm): 5 x 4 x 0.9
- Radiant sensitive area (in mm<sup>2</sup>): 7.5
- AEC-Q101 qualified
- Daylight blocking filter matched with 850 nm to 890 nm emitters
- High radiant sensitivity
- Excellent Ira linearity
- · Fast response times
- Angle of half sensitivity: φ = ± 65°
- Floor life: 72 h, MSL 4, according to J-STD-020
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



- · High speed photo detector
- Small signal detection
- · Proximity sensors

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.1</sub> (nm)	
VEMD5160X01	26	± 65	700 to 1070	

#### Note

· Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD5160X01	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Top view		
VEMD5160X01-GS15	Tape and reel	MOQ: 5000 pcs, 5000 pcs/reel	Top view		

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	20	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	$P_V$	240	mW	
Junction temperature		Tj	110	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +110	°C	
Soldering temperature	According to reflow solder profile fig. 8	$T_{sd}$	260	°C	
Thermal resistance junction / ambient	According to EIA / JESD51	$R_{thJA}$	350	K/W	
ESD safety HBM	$\pm$ 2000 V, 1.5 k $\Omega$ , 100 pF, 3 pulses	ESD <sub>HBM</sub>	≥ 2	kV	



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BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	0.8	1.0	V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	20	-	-	V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>	-	0.2	10	nA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>D</sub>	-	80	-	pF
	V <sub>R</sub> = 3 V, f = 1 MHz, E = 0	C <sub>D</sub>	-	35	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo	-	350	-	mV
Temperature coefficient of Vo	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	TK <sub>Vo</sub>	-	-2.6	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	l <sub>k</sub>	-	26	-	μΑ
Temperature coefficient of I <sub>k</sub>	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 835 \text{ nm}$	TK <sub>Ik</sub>	-	0.1	-	%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	20	26	31	μΑ
	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 890 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	-	38	-	μΑ
Angle of half sensitivity		φ	-	± 65	-	deg
Wavelength of peak sensitivity		$\lambda_{p}$	-	840	-	nm
Range of spectral bandwidth		λ <sub>0.1</sub>	-	700 to 1070	-	nm
Rise time	$V_R = 5 \text{ V}, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>	-	30	-	ns
Fall time	$V_R = 5 \text{ V}, R_L = 50 \Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>	-	30	-	ns

## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

Basic characteristics graphs to be extended to 110 °C ambient temperatures where applicable.

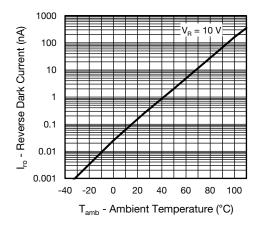


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

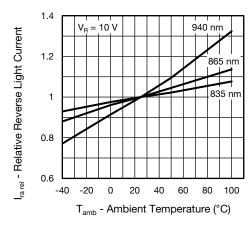


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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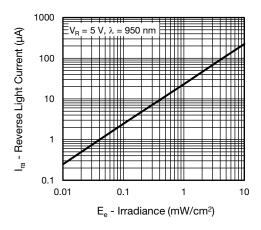


Fig. 3 - Reverse Light Current vs. Irradiance

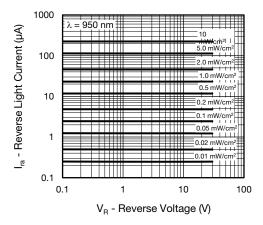


Fig. 4 - Reverse Light Current vs. Reverse Voltage

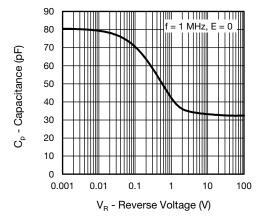


Fig. 5 - Diode Capacitance vs. Reverse Voltage

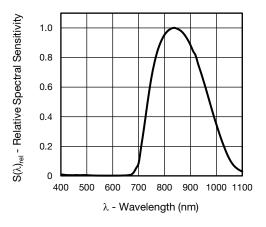


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

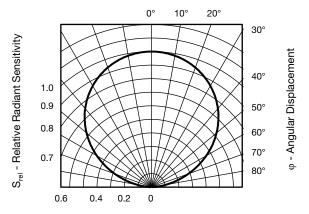
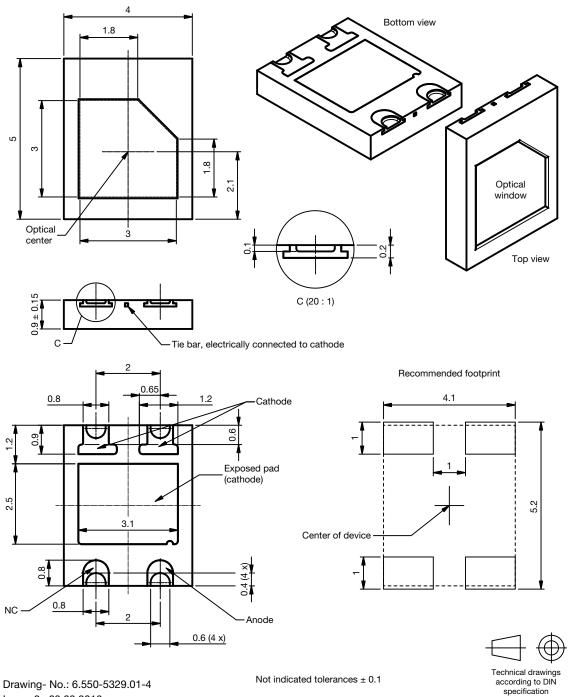


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

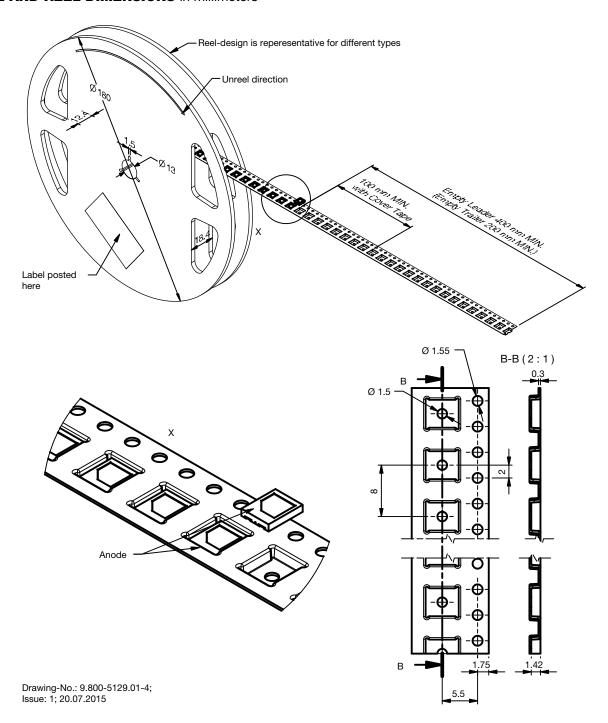


## **PACKAGE DIMENSIONS** in millimeters



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## TAPE AND REEL DIMENSIONS in millimeters





### **SOLDER PROFILE**

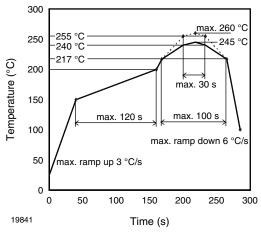


Fig. 8 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020D

## **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %.



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Vishay

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